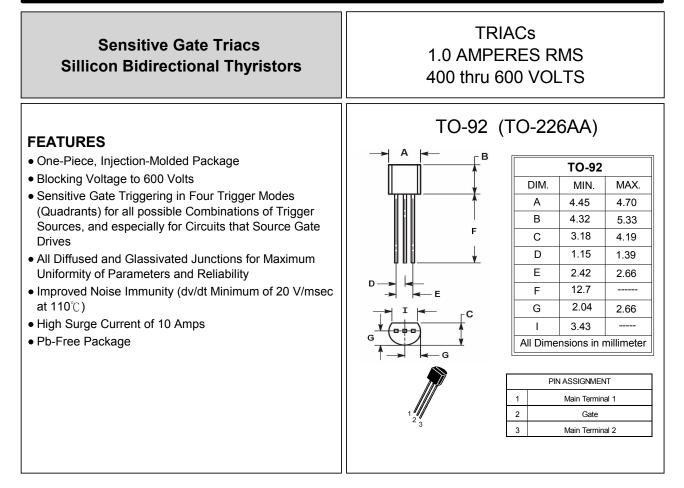
LITE ON SEMICONDUCTOR

T1M3F-A SERIES



MAXIMUM RATINGS (Tj= 25°C unless otherwise noticed)

Rating	Symbol	Value	Unit
Peak Repetitive Off– State Voltage (TJ= -40 to 110°C, Sine Wave, 50 to 60 Hz; Gate Open)			
T1M3F400A T1M3F600A	Vdrm, Vrrm	400 600	Volts
On-State RMS Current Full Cycle Sine Wave 50 to 60 Hz (Tc = 50℃)		1.0	Amp
Peak Non-Repetitive Surge Current Full Cycle Sine Wave 60 Hz (Tj =25℃)	Ітѕм	10.0	Amps
Circuit Fusing Consideration (t = 8.3 ms)	l ² t	0.60	A ² s
Peak Gate Power ($t \leq$ 2.0us ,Tc = 80 $^\circ \!\! C)$	Рдм	5.0	Watt
Average Gate Power (Tc = 80 $^\circ\!\mathbb{C},t\leq$ 8.3 ms)	PG(AV)	0.1	Watt
Peak Gate Current ($t \leq 2.0 \text{us}$,Tc = 80 $^\circ \text{C}$)	lgм	1.0	Amp
Peak Gate Voltage (t \leq 2.0us ,Tc = 80°C)	Vgм	5.0	Volts
Operating Junction Temperature Range	TJ	-40 to +110	°C
Storage Temperature Range	Tstg	-40 to +150	°C
Notice: (1) VDRM and VRRM for all types can be applied on a continuous basis. Blocking	RE	V. 3, Oct-2010, K	TXD13

voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance - Junction to Lead - Junction to Case - Junction to Ambient	RthJL RthJC RthJA	60 75 150	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8 from Case for 10 Seconds	TL	260	°C

ELECTRICAL CHARACTERISTICS (Tj=25°C unless otherwise noted)

Characteristics	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					•
Peak Reptitive Forward or Reverse Blocking CurrentTj =25 $^{\circ}$ C(VD=Rated VDRM and VRRM; Gate OPen)Tj =110 $^{\circ}$ C	Idrm Irrm			10 100	uA uA
ON CHARACTERISTICS					
Peak Forward On-State Voltage (ITM=± 1A Peak @Tp \leq 2.0 ms, Duty Cycle \leq 2%)	Vтм			1.9	Volts
Gate Trigger Current (V _D = 12 Vdc; R _L = 100 Ohms)	IGT1 IGT2 IGT3 IGT4	 	 	3.0 3.0 3.0 5.0	mA
Holding Current (VD = 12 V, Initiating Current = ± 200 mA, Gate Open)	lн		1.5	10	mA
Turn-On Time (VD = Rated VDRM , ITM = 1.0 A pk, IG = 25 mA)	tgt		2		us
Gate Trigger Voltage (V _D = 12 Vdc; R _L =100 Ohms)	VGT1 VGT2 VGT3 VGT4	 	0.66 0.77 0.84 0.88	2.0 2.0 2.0 2.5	Volts
Latching Current (VD=12V,IG= 10 mA)	IL1 IL2 IL3 IL4	 	1.6 10.5 1.5 2.5	15 20 15 15	mA
Gate Non-Trigger Voltage (VD= 12V, RL= 100 Ohms , TJ=110 $^\circ \!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!\!$	Vgd	0.1			Volts

DYNAMIC CHARACTERISTICS

Critical Rate of Rise of Off-State Voltage (VD=Rated VDRM,Exponential Waveform, Gate Open, TJ=110℃)	dv/dt	20	60	 V/us	
					1

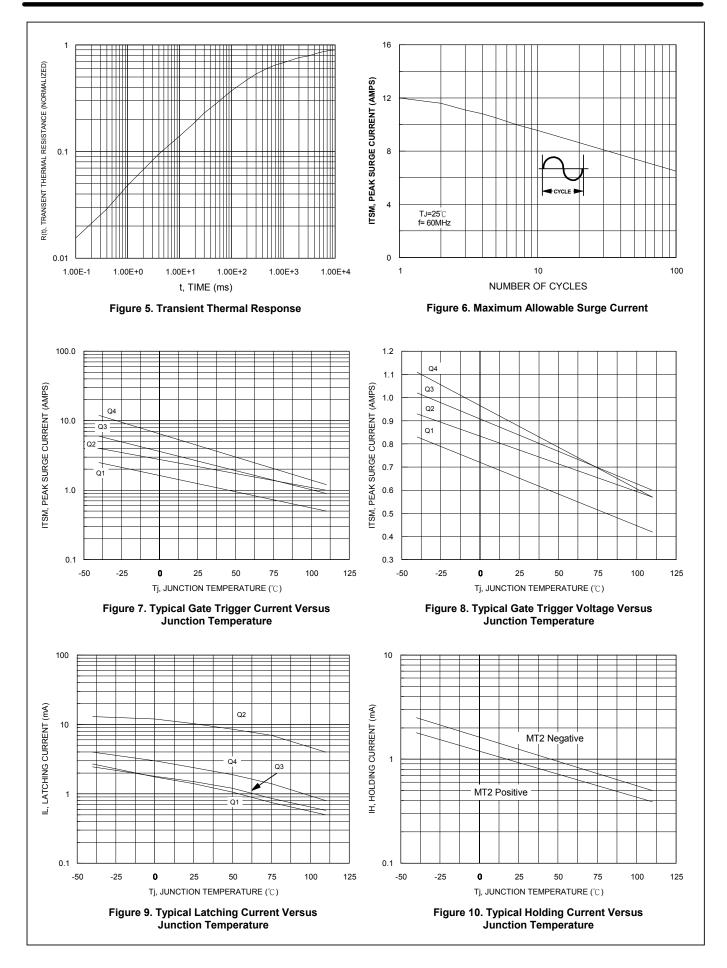
RATING AND CHARACTERISTIC CURVES T1M3F-A SERIES

1.2 0.8 IT(RMS), RMS ON-STATE CURRENT(AMPS) IT(RMS), RMS ON-STATE CURRENT(AMPS) 0.7 1.0 0.6 0.8 0.5 0.4 0.6 0.3 0.4 0.2 0.2 0.1 0.0 0.0 0 100 125 0 100 125 25 50 75 25 50 75 Ta, AMBIENT TEMPERATURE(°C) Tc, CASE TEMPERATURE(℃) Figure 1. RMS Current Deratiing Versus Figure 2. RMS Current Deratiing Versus Case Temperature Ambient Temperature 1.2 10 1.0 P(AV), POWER PISSIPATION (WATTS) 0.8 tpy. ITM, INSTANTANEOUS ON-STATE CURRENT (AMP) 1 max. 0.6 1 0.4 0.2 Ĩ . 0.0 0.1 0.0 0.1 0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9 1.0 IT(RMS), RMS ON-STATE CURRENT (AMPS) I Figure 3. Power Dissipation 1 1 0.01 0.4 0.8 1.2 2.4 2.8 1.6 2.0 VTM, INSTANTANEOUS ON-STATE VOLTAGE (VOLTS) Figure 4. On-State Characteristics

LITE ON

RATING AND CHARACTERISTIC CURVES T1M3F-A SERIES

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